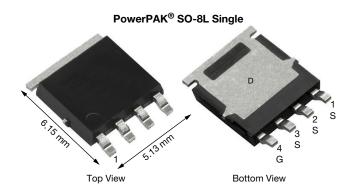


www.vishay.com

Vishay Siliconix

Automotive P-Channel 80 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	-80				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0173				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0265				
I _D (A)	-46				
Configuration	Single				
Package	PowerPAK SO-8L				

FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % Rq and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





ROHS COMPLIANT HALOGEN FREE

G
O D
P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless	otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-80	V	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current	T _C = 25 °C	T _C = 25 °C			
	T _C = 125 °C	I _D	-26.5		
Continuous source current (diode conduction)		I _S	-62	Α	
Pulsed drain current ^a		I _{DM}	-130		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-42		
Single pulse avalanche energy	L = U.1 IIII	E _{AS}	88	mJ	
Maximum power dissipation ^a	T _C = 25 °C	D	68	W	
	T _C = 125 °C	P _D	22	VV	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	
Soldering recommendations (peak temperature) c, d			260	-0	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount b	R_{thJA}	68	°C/W
Junction-to-case (drain)		R_{thJC}	2.2	C/VV

Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. When mounted on 1" square PCB (FR4 material)
- c. See solder profile (www.vishay.com/doc?73257). The PowerPAK SO-8L is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- d. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static		-					•	
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = -250 μA	-80	-	-	V	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V _{GS} , I _D = -250 μA	-1.5	-2.0	-2.5	V	
Gate-source leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$		-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -80 V	-80				
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V _{DS} = -80 V, T _J = 125 °C	-	-	-50	μA	
		V _{GS} = 0 V	V _{DS} = -80 V, T _J = 175 °C	-	-	-250		
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	$V_{DS} \le -5 \text{ V}$	-15	-	-	Α	
		V _{GS} = -10 V	I _D = -10 A	-	0.0143	0.0173		
Drain course en etata registance 3		V _{GS} = -10 V	I _D = -10 A, T _J = 125 °C	-	-	0.0269	Ω	
Drain-source on-state resistance a	R _{DS(on)}	V _{GS} = -10 V	I _D = -10 A, T _J = 175 °C	-	-	0.0322		
		V _{GS} = -4.5 V	I _D = -6 A	-	0.0219	0.0265	1	
Forward transconductance b	9 _{fs}	V _{DS} =	-15 V, I _D = -10 A	-	29	-	S	
Dynamic ^b								
Input capacitance	C _{iss}			-	4336	5900		
Output capacitance	Coss	$V_{GS} = 0 V$	V _{DS} = -25 V, f = 1 MHz	-	1495	2100	рF	
Reverse transfer capacitance	C _{rss}	7		-	53	75		
Total gate charge ^c	Qg			-	52	80		
Gate-source charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -40 \text{ V}, I_{D} = -10 \text{ A}$	-	13	-	nC	
Gate-drain charge c	Q _{gd}			-	5	-		
Gate resistance	R _g		f = 1 MHz	0.5	1.0	1.5	Ω	
Turn-on delay time ^c	t _{d(on)}			-	16	25		
Rise time ^c	t _r	V _{DD} =	= -40 V, $R_L = 4 \Omega$,	-	5	10		
Turn-off delay time ^c	t _{d(off)}		$V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$	-	33	55	ns	
Fall time ^c	t _f			-	6	12		
Source-Drain Diode Ratings and Chara	acteristics ^b							
Pulsed current ^a	I _{SM}			-	-	-130	Α	
Forward voltage	V_{SD}	l _F =	= -10 A, V _{GS} = 0	-	-0.82	-1.2	V	
Body diode reverse recovery time	t _{rr}			-	50	100	ns	
Body diode reverse recovery charge	Q _{rr}]	1 A di/dt 100 A/vo	-	54	110	nC	
Reverse recovery fall time	ta	I _F = -10	0 A, di/dt = 100 A/μs	-	20	-		
Reverse recovery rise time	t _b	7		-	30	-	ns	
Body diode peak reverse recovery current	I _{RM(REC)}			-	-1.95	-	Α	

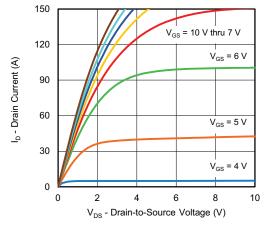
Notes

- a. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- b. Guaranteed by design, not subject to production testing
- c. Independent of operating temperature

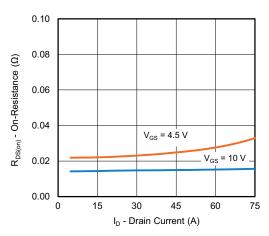
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



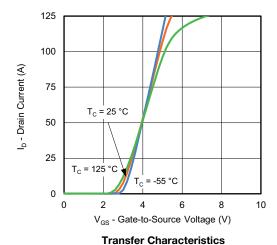
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

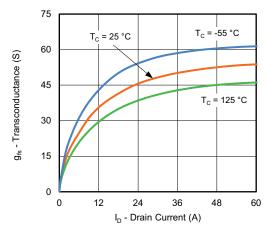


Output Characteristics

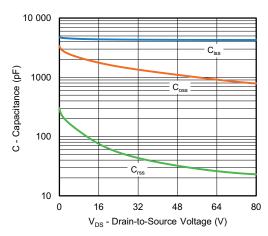


On-Resistance vs. Drain Current

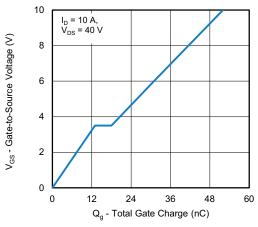




Transconductance



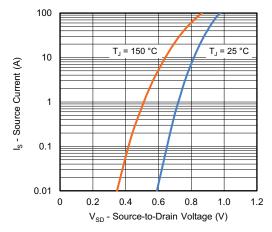
Capacitance



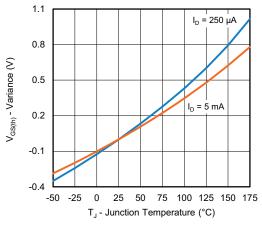
Gate Charge



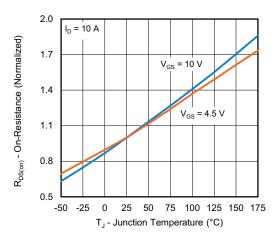
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



Source Drain Diode Forward Voltage



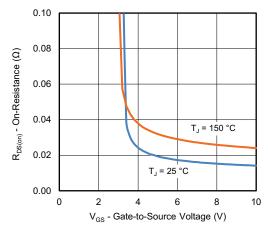
Threshold Voltage



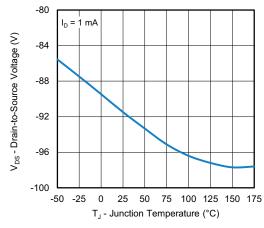
On-Resistance vs. Junction Temperature

Note

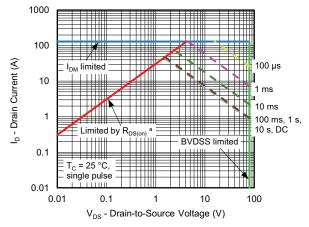
a. V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified



On-Resistance vs. Gate-to-Source Voltage



Drain Source Breakdown vs. Junction Temperature

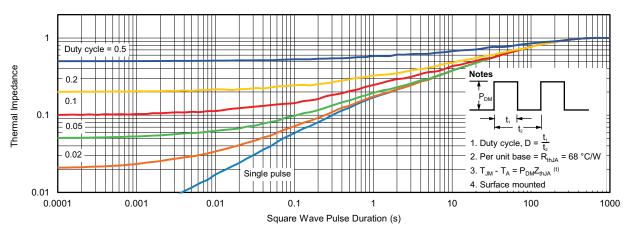


Safe Operating Area

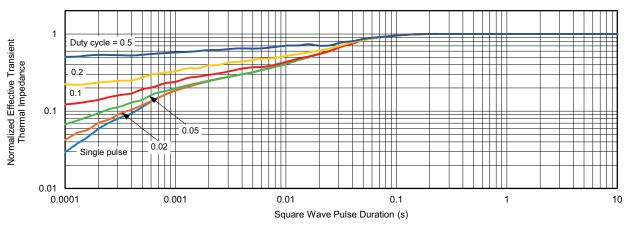
For technical questions, contact: automostechsu



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Case

Note

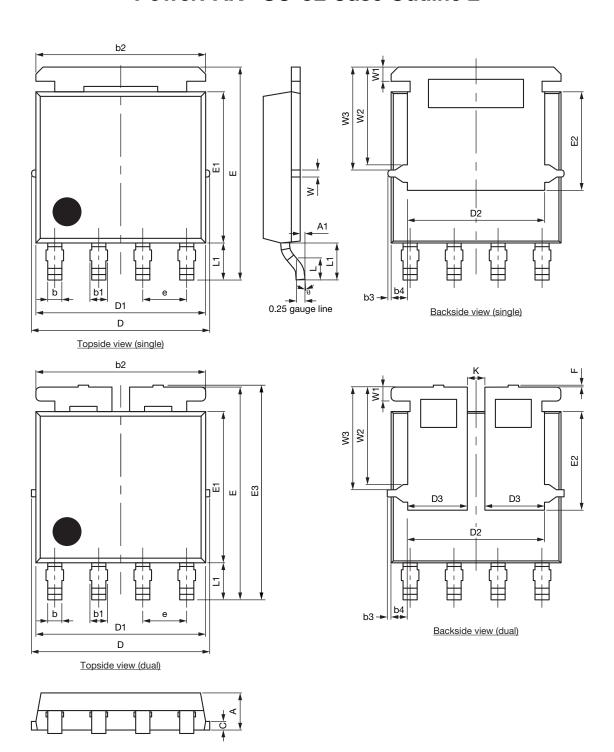
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77266.



PowerPAK® SO-8L Case Outline 2





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DIM	MILLIMETERS			INCHES			
DIM.	MIN.	NOM.	MAX.	MIN. NOM.		MAX.	
Α	1.00	1.07	1.14	0.039	0.042	0.045	
A1	0.00	-	0.127	0.00	-	0.005	
b	0.33	0.41	0.48	0.013	0.016	0.019	
b1	0.44	0.51	0.58	0.017	0.020	0.023	
b2	4.80	4.90	5.00	0.189	0.193	0.197	
b3		0.094			0.004		
b4		0.47			0.019		
С	0.20	0.25	0.30	0.008	0.010	0.012	
D	5.00	5.13	5.25	0.197	0.202	0.207	
D1	4.80	4.90	5.00	0.189	0.193	0.197	
D2	3.86	3.96	4.06	0.152	0.156	0.160	
D3	1.63	1.73	1.83	0.064	0.068	0.072	
е		1.27 BSC		0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246	
E1	4.27	4.37	4.47	0.168	0.172	0.176	
E2	2.75	2.85	2.95	0.108	0.112	0.116	
E3	6.05	6.22	6.40	0.238	0.245	0.252	
F	-	-	0.15	-	-	0.006	
L	0.62	0.72	0.82	0.024	0.028	0.032	
L1	0.92	1.07	1.22	0.036	0.042	0.048	
K	0.51				0.020		
W	0.23		0.009				
W1	0.41		0.016				
W2	2.82		0.111				
W3	2.96			0.117			
θ	0°	-	10°	0°	-	10°	

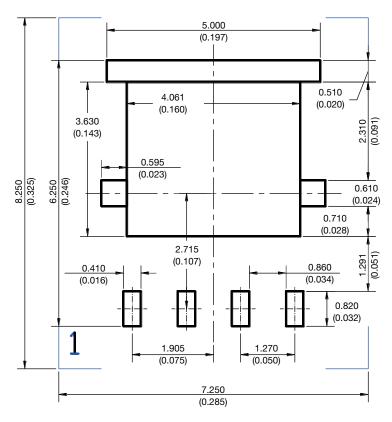
DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



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